



# PJP9NA90 / PJF9NA90 / PJZ9NA90

## 900V N-Channel MOSFET

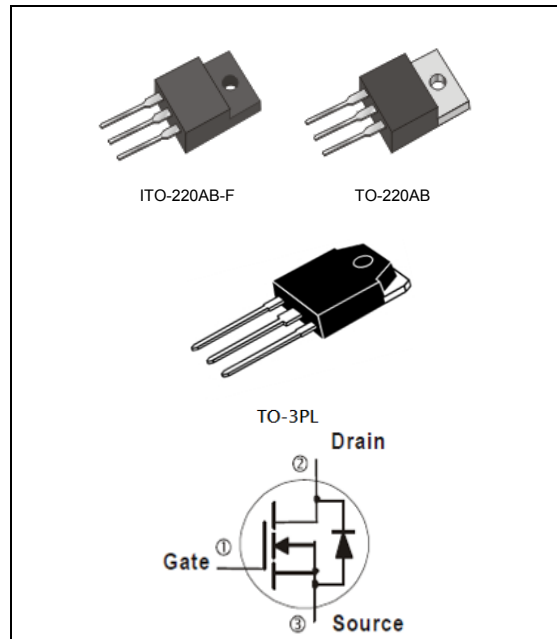
<b>Voltage</b>	<b>900 V</b>	<b>Current</b>	<b>9 A</b>
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### Features

- $R_{DS(ON)}, V_{GS}@10V, I_D@4.5A < 1.4\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std.  
(Halogen Free)

### Mechanical Data

- Case : TO-220AB, ITO-220AB-F, TO-3PL Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-220AB Approx. Weight : 0.065 ounces, 1.859 grams
- ITO-220AB-F Approx. Weight : 0.068 ounces, 1.945 grams
- TO-3PL Approx. Weight : 0.182 ounces, 5.174grams



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	TO-220AB	ITO-220AB-F	TO-3PL	UNITS
Drain-Source Voltage		$V_{DS}$	900			V
Gate-Source Voltage		$V_{GS}$	±30			V
Continuous Drain Current		$I_D$	9			A
Pulsed Drain Current		$I_{DM}$	36			A
Single Pulse Avalanche Energy <sup>(Note 1)</sup>		$E_{AS}$	823			mJ
Power Dissipation	$T_C=25^\circ\text{C}$	$P_D$	205	68	240	W
	Derate above $25^\circ\text{C}$		1.64	0.54	1.92	W/ $^\circ\text{C}$
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150			$^\circ\text{C}$
Typical Thermal resistance						
-	Junction to Case	$R_{\theta JC}$	0.61	1.84	0.52	$^\circ\text{C/W}$
-	Junction to Ambient	$R_{\theta JA}$	62.5	120	50	

- Limited only By Maximum Junction Temperature



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### Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	900	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	2	-	4	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=4.5A$	-	1.1	1.4	$\Omega$
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=900V, V_{GS}=0V$	-	0.03	1.0	$\mu A$
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 30V, V_{DS}=0V$	-	$\pm 10$	$\pm 100$	nA
Diode Forward Voltage	$V_{SD}$	$I_S=9A, V_{GS}=0V$	-	-	1.4	V
<b>Dynamic</b> (Note 4)						
Total Gate Charge	$Q_g$	$V_{DS}=720V, I_D=9A,$ $V_{GS}=10V$ (Note 2,3)	-	31	-	nC
Gate-Source Charge	$Q_{gs}$		-	8	-	
Gate-Drain Charge	$Q_{gd}$		-	12	-	
Input Capacitance	$C_{iss}$	$V_{DS}=25V, V_{GS}=0V,$ $f=1.0\text{MHz}$	-	1634	-	pF
Output Capacitance	$C_{oss}$		-	143	-	
Reverse Transfer Capacitance	$C_{rss}$		-	7.1	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=450V, I_D=9A,$ $R_G=25\Omega$ (Note 2,3)	-	22	-	ns
Turn-On Rise Time	$t_r$		-	31	-	
Turn-Off Delay Time	$t_{d(off)}$		-	56	-	
Turn-Off Fall Time	$t_f$		-	31	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_S$	---	-	-	9	A
Maximum Pulsed Drain-Source Diode Forward Current	$I_{SM}$	---	-	-	36	A
Reverse Recovery Time	$t_{rr}$	$V_{GS}=0V, I_S=9A$	-	657	-	ns
Reverse Recovery Charge	$Q_{rr}$	$di_F/dt=100A/\mu s$ (Note 2)	-	5.6	-	$\mu C$

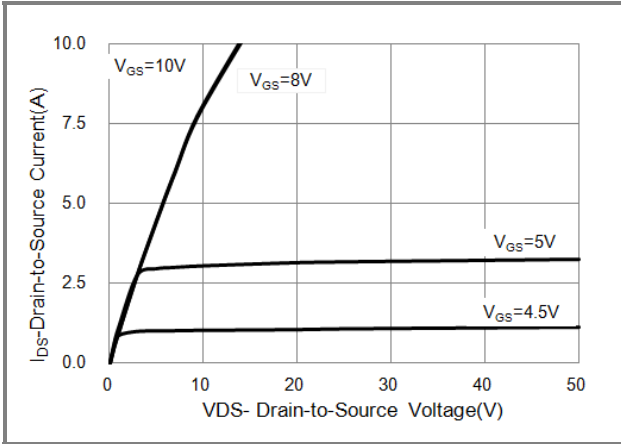
NOTES :

1.  $L=30\text{mH}, I_{AS}=7.1A, V_{DD}=50V, R_G=25\text{ohm}$ , Starting  $T_J=25^\circ\text{C}$
2. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
3. Essentially independent of operating temperature typical characteristics.
4. Guaranteed by design, not subject to production testing

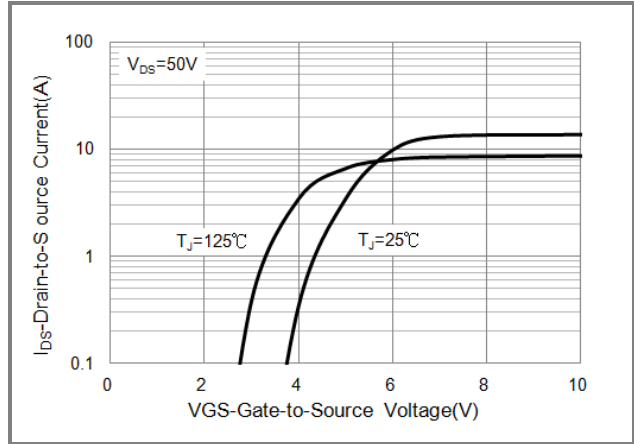


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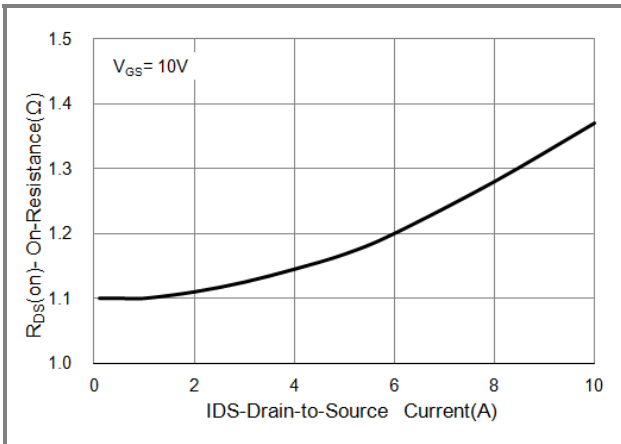
## TYPICAL CHARACTERISTIC CURVES



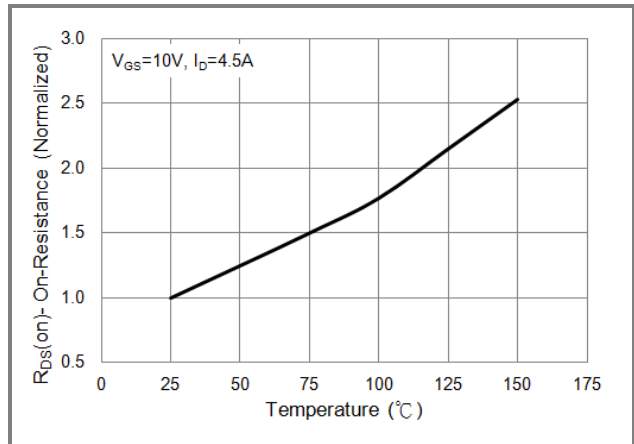
**Fig.1 Output Characteristics**



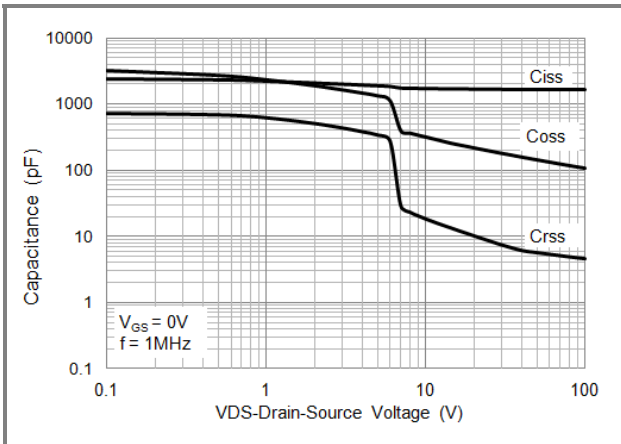
**Fig.2 Transfer Characteristics**



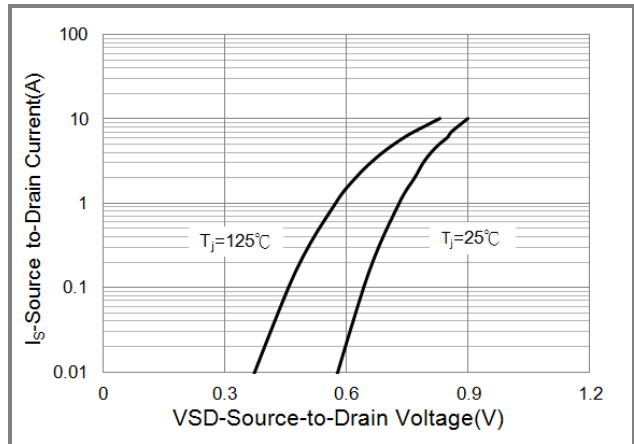
**Fig.3 On-Resistance vs. Drain Current**



**Fig.4 On-Resistance vs. Junction Temperature**



**Fig.5 Capacitance vs. Drain-Source Voltage**



**Fig.6 Source-Drain Diode Forward Voltage**



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## TYPICAL CHARACTERISTIC CURVES

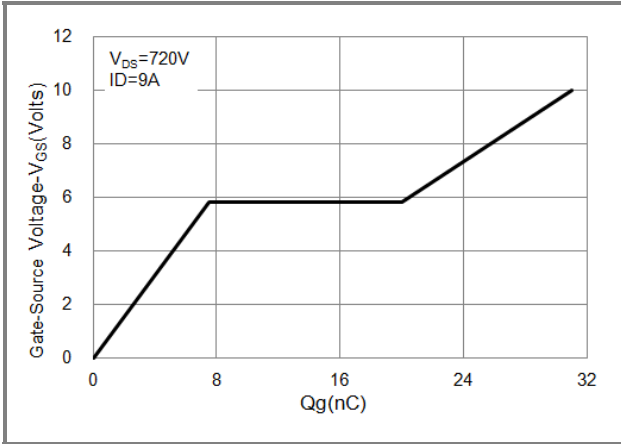


Fig.7 Gate Charge

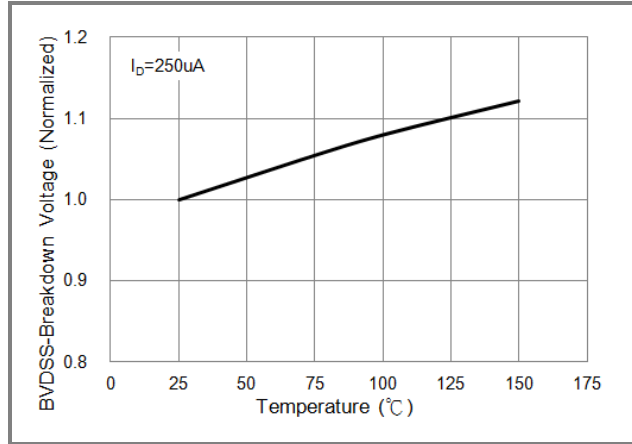


Fig.8 BVDS vs. Junction Temperature

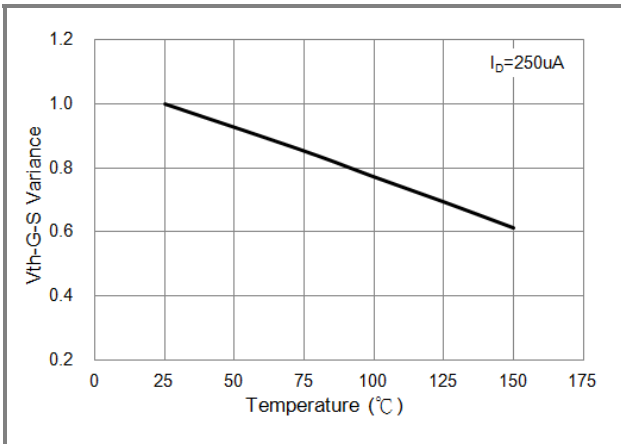


Fig.9 Threshold Voltage Variation with Temperature

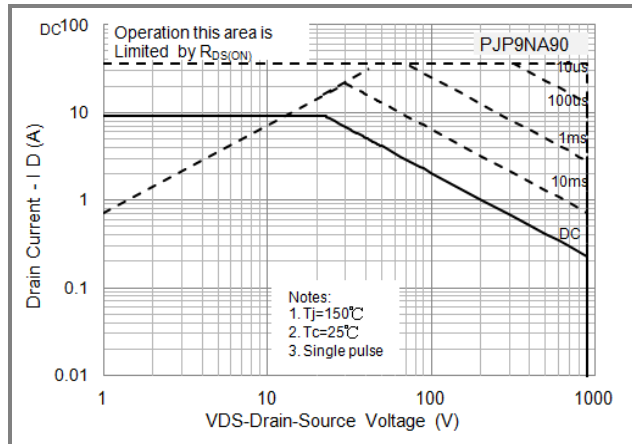


Fig.10 Maximum Safe Operating Area

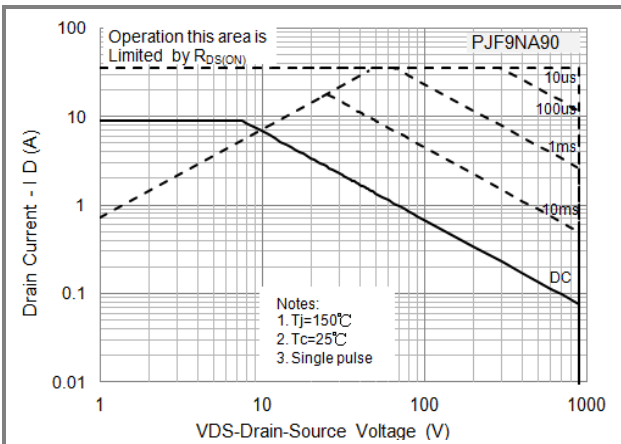


Fig.11 Maximum Safe Operating Area

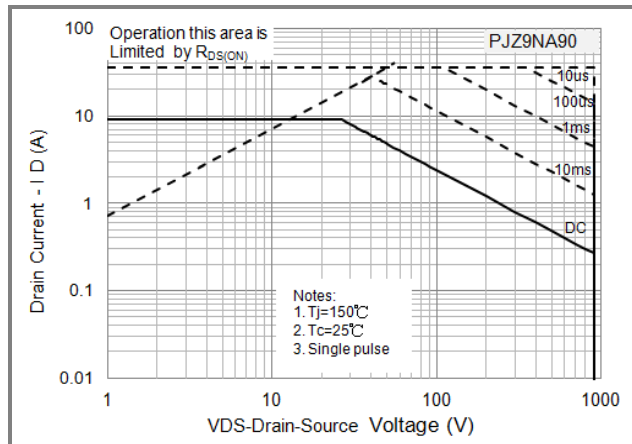


Fig.12 Maximum Safe Operating Area



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## TYPICAL CHARACTERISTIC CURVES

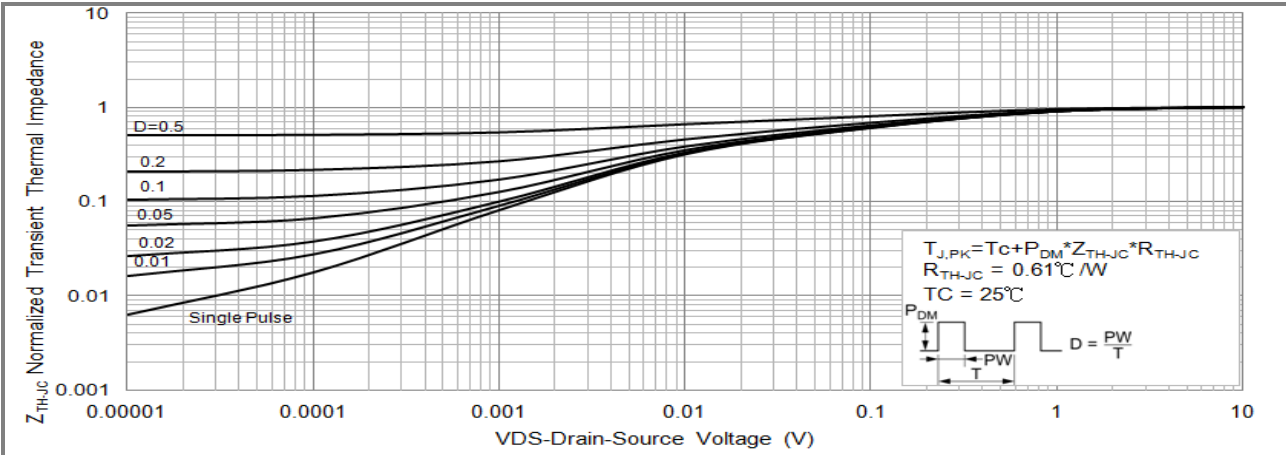


Fig.13 PJP9NA90 Normalized Transient Thermal Impedance vs. Pulse Width

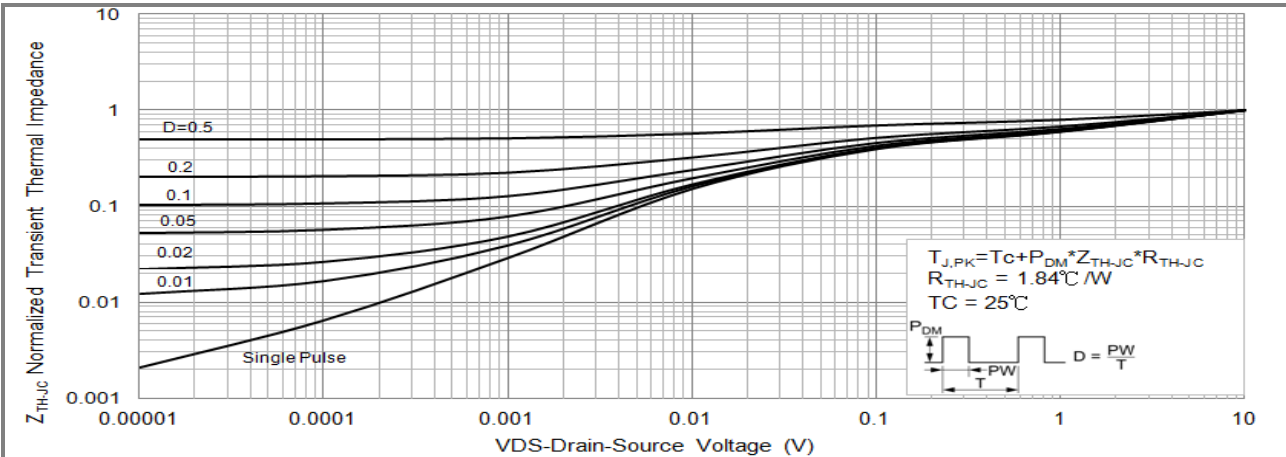


Fig.14 PJF9NA90 Normalized Transient Thermal Impedance vs. Pulse Width

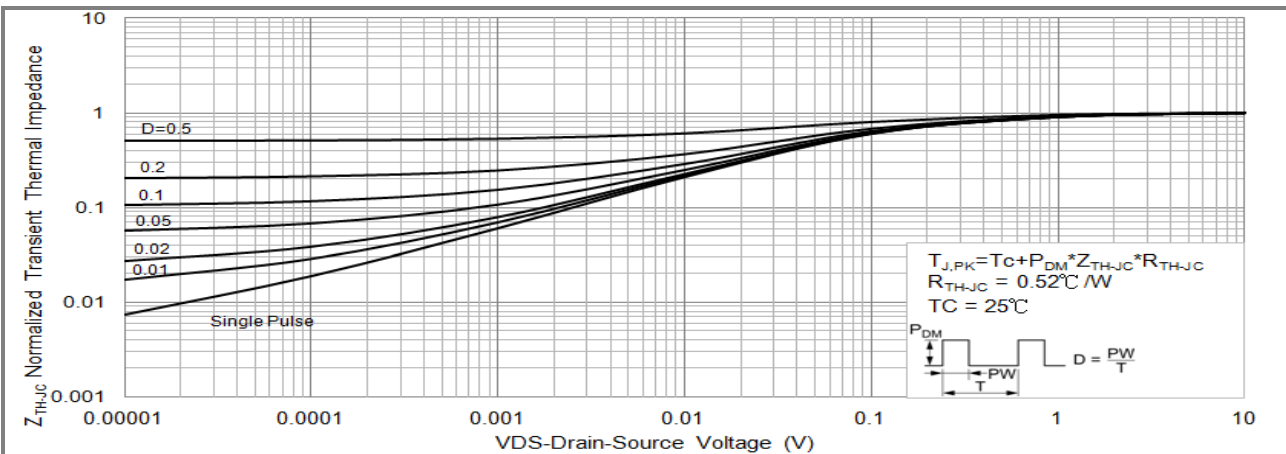
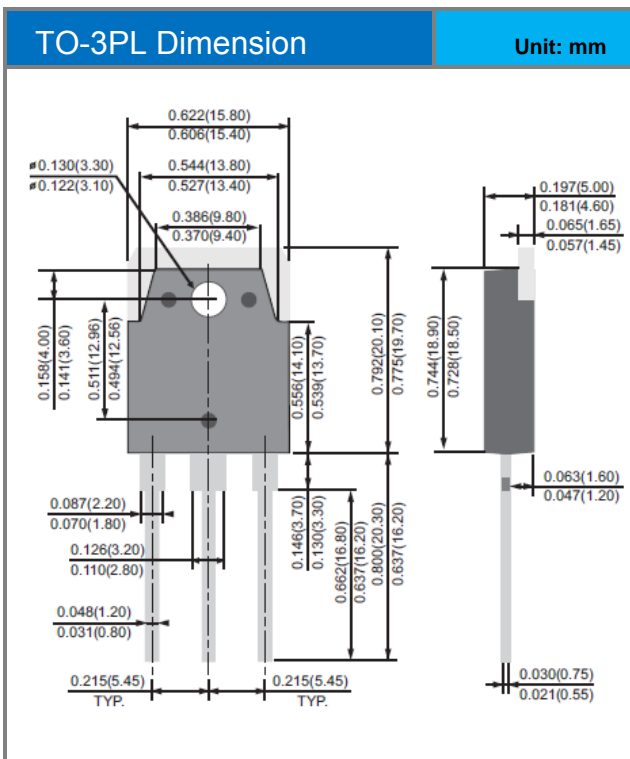
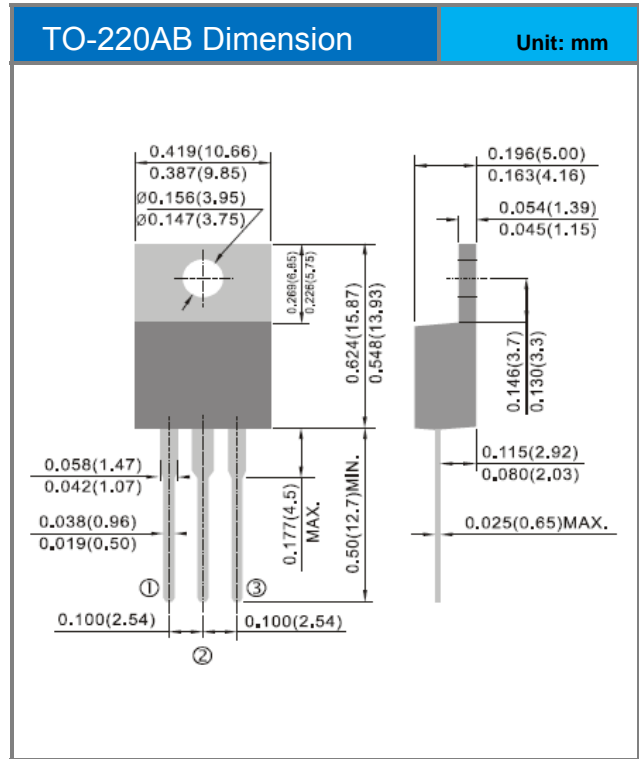
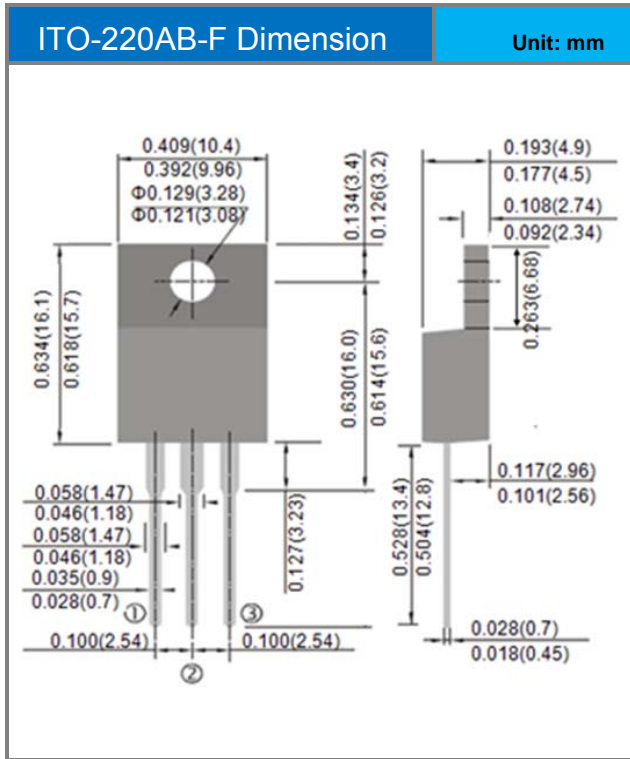


Fig.15 PJZ9NA90 Normalized Transient Thermal Impedance vs. Pulse Width



# PJP9NA90 / PJF9NA90 / PJZ9NA90

## Packaging Information





## PJP9NA90 / PJF9NA90 / PJZ9NA90

### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJP9NA90_TO_00001	TO-220AB	50pcs / Tube	P9NA90	Halogen free
PJF9NA90_TO_00001	ITO-220AB-F	50pcs / Tube	F9NA90	Halogen free
PJZ9NA90_TO_10001	TO-3PL	30pcs / Tube	Z9NA90	Rohs



## **PJP9NA90 / PJF9NA90 / PJZ9NA90**

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